IDEAL SEMICONDUCTOR INC. IS

"Your Best Defense Against Obsolescence"

NE542 Dual Low-Noise Preamplifier

Product Specification

Linear Products

DESCRIPTION

The NE542 is a dual preamplifier for the amplification of low level signals in applications requiring optimum noise performance. Each of the two amplifiers is completely independent, with individual internal power supply decoupler-regulator, providing 110dB supply rejection and 70dB channel separation. Other outstanding features include high gain (104dB), large output voltage swing (V_{CC}-2V_{P-P}), and internal compensation to 10dB. The NE542 operates from a single supply across a range of 9 to 24V.

The NE542 is ideal for use in stereo phono, tape, or microphone preamps and other applications requiring low noise amplification of small signals.

FEATURES

- Low noise 0.7µV total input noise
- High gain 104dB open-loop
- · Single supply operation

• Short-circuit protected

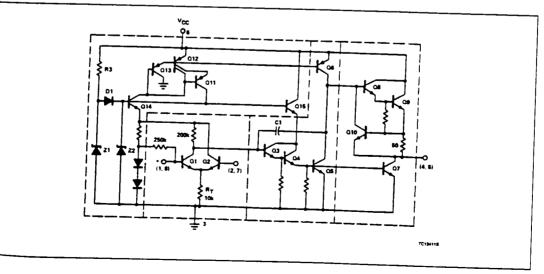
• High slew rate 5V/µs

- Wide supply range 9 to 24V
- Power supply rejection 110dB
- Large output voltage swing (V_{CC}-2V_{P-P})
- Wide bandwidth 15MHz unity gain
- Power bandwidth 100kHz (15VP-P)
- · internally-compensated (stable at 10dB)

ORDERING INFORMATION

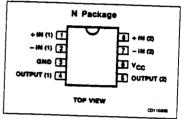
DESCRIPTION	TEMPERATURE RANGE	ORDER CODE
8-Pin Plastic DIP	0 to +70°C	NE542N

EQUIVALENT CIRCUIT



46721 Fremont Blvd. • Fremont, California 94538 • Telephone: (510) 226-7000 • Fax: (510) 226-1564

PIN CONFIGURATION



APPLICATIONS

- Tape preamplifier
- · Phono preamplifier
- Microphone preamplifier

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Dual Low-Noise Preamplifier

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT V mW °C	
Vcc	Supply voltage	+ 24		
PD	Power dissipation	500		
TA	Operating ambient temperature range	0 to +70		
TSTG	Storage temperature range	-65 to +150		
T _{SOLD} Lead soldering temperature (10sec max)		+ 300	= dc	

DC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$; $V_{CC} = 14V$, unless otherwise specified.

	PARAMETER	METER TEST CONDITIONS	LIMITS			
	Supply wells		Min	Тур	Max	UNIT
-uc -lcc	Supply voltage Supply current		9		24	v
R _{IN}	Input resistance	$V_{CC} = 9$ to 18V, $R_L = \infty$		9	15	mА
	Positive input Negative input			100 200		kΩ
Rout	Output resistance	Open-loop		150		kΩ Ω

AC ELECTRICAL CHARACTERISTICS T_A = 25°C; V_{CC} = 14V, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			
			Min	Тур	Max	UNIT
A _V	Voltage gain	Open-loop	<u>+</u>	160,000		
l _{IN}	Negative Input current				0.5	+
	Output current	Source Sink (linear operation)	8	14 3	0.5	mA mA
VOUT	Output voltage swing		V _{CC} -2.5	V _{CC} -2		V V
SR	Small signal bandwidth Slew rate			15 5		MHz
Paw	Power bandwidth	15V _{P.P}	<u>॑</u>			V/µs
V _{IN}	Maximum input voltage	Linear operation, < 2.5% distortion		100		kHz
PSRR	Power supply rejection ratio	f = 60, 120Hz f = 1kHz		100 110	300	mV _{RM} dB dB
	Channel separation	f = 1kHz	40	70		<u> </u>
THD	Total harmonic distortion	40dB gain, f = 1kHz				dB
	Total equivalent input noise	R _S = 600Ω, 100 - 10,000Hz	<u> </u>	0.1	0.3	%
No	Noise figure	$ \begin{array}{l} R_{S}=50k\Omega, \ 10-10,000Hz \\ R_{S}=20k\Omega, \ 10-10,000Hz \\ R_{S}=10k\Omega, \ 10-10,000Hz \\ R_{S}=5k\Omega, \ 10-10,000Hz \end{array} $		1.2 1.2 1.5 2.4	1.2	μV _{RMS} dB dB dB dB

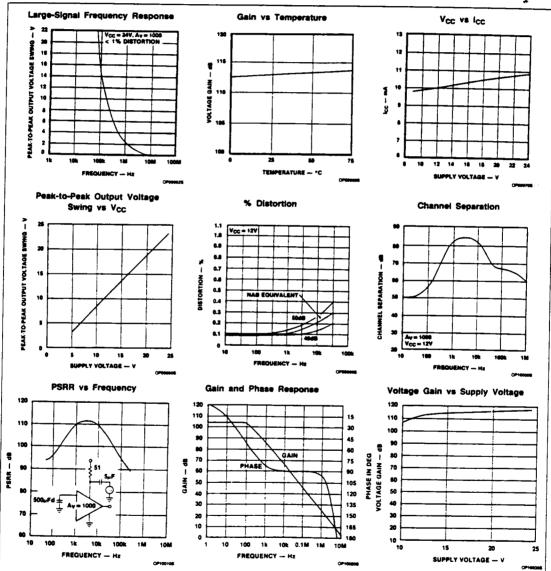
NE542

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Dual Low-Noise Preamplifier

TYPICAL PERFORMANCE CHARACTERISTICS



Product Specification

NE542

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